QUARTZ CRYSTAL OSCILLATOR

4

■ GENERAL DESCRIPTION

The NJU6361A is a C-MOS quartz crystal oscillator which consists of an oscillation amplifier, 3-stage divider, output frequency selector and inverter output buffer.

The oscillation frequency is as wide as up to 50MHz and the symmetry of 45-55% is realized over full oscillation frequency range.

The oscillation amplifier incorporates feed-back resistance and oscillation capacitors(Cg, Cd), therefore, it requires no external component except quartz crystal.

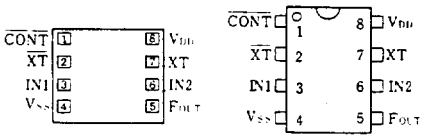
The 3-stage divider outputs f_o, $f_o/2$, $f_o/4$ and $f_o/8$ to the output frequency selector and it determined one output frequency according to the combination of two input-signal.

The inverter output buffer is C-MOS compatible and capable of 10 LSTTL driving.

■ PACKAGE OUTLINE

NJU6361AC NJU6361AE

■ PIN CONFIGURATION/PAD LOCATION



■ FEATURES

- Operating Voltage -- 3.0~6.0V
- Maximum Oscillation Frequency -- 50MHz
- Low Operating Current
- High Fan-out -- LSTTL 10
- Inverter Output Buffer
- Selected Frequency Output
  Only one frequency out of f_o, $f_o/2$, $f_o/4$ and $f_o/8$ output
- Oscillation Capacitors Cg and Cd on-chip
- Oscillation and Output Stand-by Function
- Package Outline -- CHIP/EMP 8
- C-MOS Technology

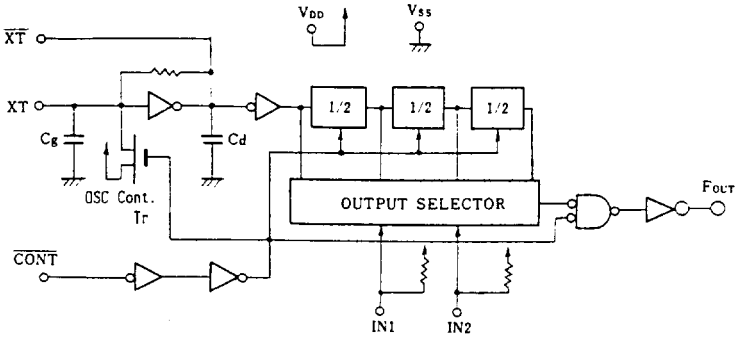
■ COORDINATES

Unit: μm

No.	PAD	X	Y
1	$\overline{CONT}$	165	651
2	$\overline{XT}$	165	484
3	IN1	165	317
4	V_{SS}	165	149
5	F_{OUT}	1113	149
6	IN2	1113	317
7	XT	1113	484
8	V_{DD}	1113	651

Chip Size : 1.28 X 0.8mm
Chip Thickness : 400μm±30μm

■ BLOCK DIAGRAM



■ TERMINAL DESCRIPTION

NO.	SYMBOL	FUNCTION
1	$\overline{CONT}$	Oscillation Stop Control and Divider Reset $\overline{CONT}$ = H: Output either one frequency from f_O, $f_O/2$, $f_O/4$, and $f_O/8$ $\overline{CONT}$ = L: Oscillation stop and Divider Reset
2	XT	Quartz Crystal Connecting Terminals
7	XT	
8	V_{DD}	+ 5V
3	IN1	3-State Divider Outputs selected by IN1 and IN2
6	IN2	IN1 / IN2 / F_{OUT}: H / H / f_O; L / H / $f_O/2$; H / L / $f_O/4$; L / L / $f_O/8$
5	F_{OUT}	Output either one frequency from f_O, $f_O/2$, $f_O/4$, and $f_O/8$
4	V_{SS}	GND

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25℃)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V_{DD}	-0.5 ~ +7.0	V
Input Voltage	V_{IN}	-0.5 ~ V_{DD}+0.5	V
Output Voltage	V_O	-0.5 ~ V_{DD}+0.5	V
Input Current	I_{IN}	±10	mA
Output Current	I_O	±25	mA
Power Dissipation (EMP)	P_D	200	mW
Operating Temperature Range	Topr	-40 ~ + 85	℃
Storage Temperature Range	Tstg	-65 ~ +150	℃

■ ELECTRICAL CHARACTERISTICS

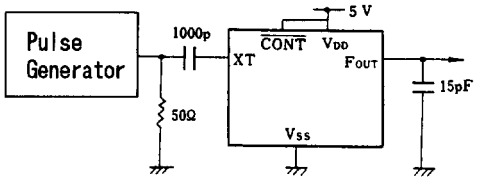
(Ta=25℃, V_{DD}=5V)

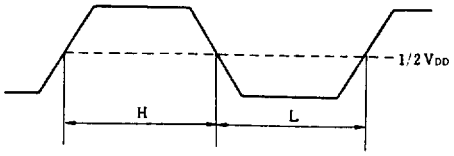
PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Operating Voltage	V_{DD}		3		6	V
Operating Current	I_{DD}	fosc=16MHz, No load			10	mA
Stand-by Current	Ist	$\overline{CONT}$,XT=V_{SS}, No load (Note)			1	μA
Input Voltage	V_{IH}		3.5		5.0	V
	V_{IL}		0		1.5	
Output Current	I_{OH}	V_{DD}=5V, V_{OH}=4.5V	4			mA
	I_{OL}	V_{DD}=5V, V_{OL}=0.5V	4			
Input Current	I_{IN}	$\overline{CONT}$, IN1, IN2 Terminals CONT, IN1, IN2=V_{SS}			400	μA
Internal Capacitor	Cg	A Version		21		pF
	Cd	A Version		23		
	Cg,Cd	P Version		-		
Max. Oscillation Freq.	f_{MAX}	V_{DD}=5V, C_L=15pF	50			MHz
Output Signal Symmetry	SYM	V_{DD}=5V, C_L=15pF at 1/2V_{DD}	45	50	55	%
Output Signal Rise Time	t_r	V_{DD}=5V, C_L=15pF, 10% - 90%			8	ns
Output Signal Fall Time	t_f	V_{DD}=5V, C_L=15pF, 90% - 10%			8	ns

Note) Excluding input current on CONT terminal.

■ MEASUREMENT CIRCUITS

(1) Output Signal Symmetry (C_L=15pF)





(2) Output Signal Rise/Fall Time (C_L=15pF)